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DISCONTINUED PRODUCT

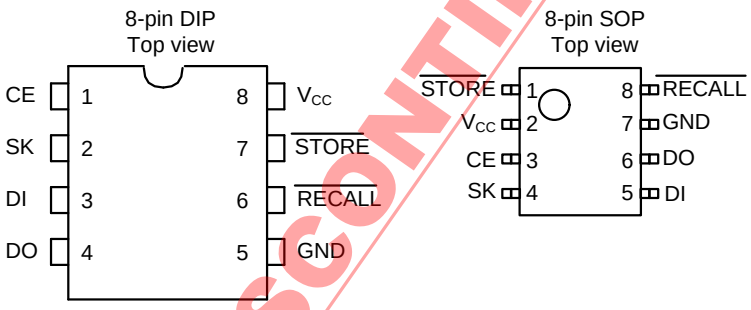
SERIAL NON-VOLATILE RAM **S-24 Series**

The S-24 Series is a non-volatile CMOS RAM, composed of a CMOS static RAM and a non-volatile electrically erasable and programmable memory (E^2PROM) to backup the SRAM. The organization is 16-word×16-bit (total 256 bits) for the S-24H45 and the S-24S45, and 8-word×8-bit (total 64 bits) for the S-24H30 and the S-24S30.

■ Features

- 256 bits
  - S-24H45 : TTL input, compatible with the X2444 of Xicor
  - S-24S45 : Schmitt input for $\overline{\text{STORE}}$ and $\overline{\text{RECALL}}$ pins
- 64 bits
  - S-24H30 : TTL input
  - S-24S30 : Schmitt input for $\overline{\text{STORE}}$ and $\overline{\text{RECALL}}$ pins
- Non-volatile functions can be controlled by software and hardware
- Erroneous store protection :≅3.5 V
- All inputs and outputs are compatible with TTL
  * Except $\overline{\text{STORE}}$ and $\overline{\text{RECALL}}$ pins for the S-24S Series
- +5-V single power supply (+5 V±10%)
- Low current consumption
  - Operating : 5 mA typ.
  - Standby : 1 µA max.
- E^2PROM store cycles : 10^5 times
- E^2PROM data retention: 10 years
- 8-pin DIP/SOP package

■ Pin Assignment



CE	Chip enable
SK	Serial clock
DI	Serial data input
DO	Serial data output
$\overline{\text{RECALL}}$	Recall
$\overline{\text{STORE}}$	Store
GND	Ground
V_{CC}	Power supply voltage (+5 V)

Figure 1

DISCONTINUED PRODUCT

■ Block Diagram

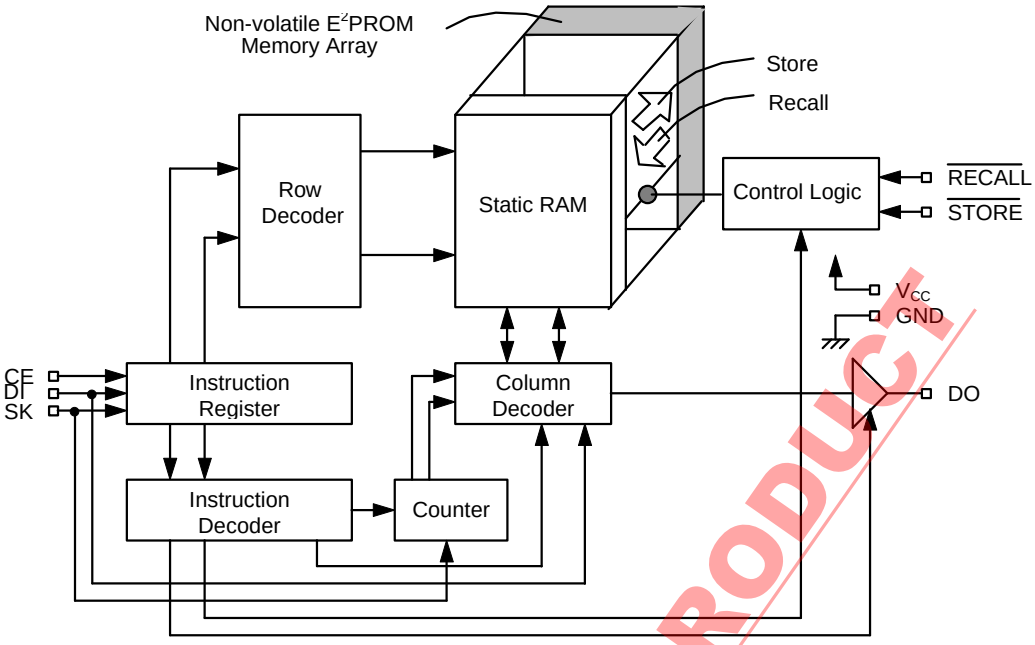


Figure 2

■ Absolute Maximum Ratings

Table 1

Parameter	Symbol	Ratings	Unit
Power supply voltage	V_{CC}	-0.3 to +6.0	V
Input voltage	V_{IN}	-0.3 to V_{CC}+0.3	V
Output voltage	V_{OUT}	0.0 to V_{CC}	V
Storage temperature under bias	T_{bias}	-50 to+95	°C
Storage temperature	T_{stg}	-65 to+150	°C

■ Recommended Operating Conditions

Table 2

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Power supply voltage	V_{CC}		4.5	5.0	5.5	V
High level input voltage 1	V_{IH}	S-24H Series : All inputs S-24S Series : CE, SK and DI	2.0	—	V_{CC}	V
High level input voltage 2	V_{IHS}	S-24S Series : $\overline{\text{STORE}}$ and $\overline{\text{RECALL}}$	3.4	—	V_{CC}	V
Low level input voltage 1	V_{IL}	S-24H Series : All inputs S-24S Series : CE, SK and DI	0.0	—	0.8	V
Low level input voltage 2	V_{ILS}	S-24S Series : $\overline{\text{STORE}}$ and $\overline{\text{RECALL}}$	0.0	—	0.8	V
Operating temperature	T_{opr}		-40	—	+85	°C

■ Pin Capacitance

Table 3

(Ta=25°C, f=1.0 MHz, V_{CC}=5 V)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Input capacitance	C_{IN}	V_{IN}=0 V	—	—	6	pF
Output capacitance	C_{OUT}	V_{OUT}=0 V	—	—	8	pF

DISCONTINUED PRODUCT

■ DC Electrical Characteristics

Table 4

(Ta=-40°C to 85°C, V_{CC}=+5 V±10%)

Parameter	Symbol	Conditions	Min.	Typ.	Max	Unit
Operating current consumption	I_{CC}	DO unloaded	—	5	10	mA
Sleep current	I_{SL}	All inputs are V_{CC}	—	—	1	µA
Standby current	I_{SB}	CE=GND, Other inputs are V_{CC}	—	—	1	µA
Store current	I_{STO}		—	5	10	mA
Input leakage current	I_{LI}	V_{IN} =GND to V_{CC}	—	0.1	1	µA
Output leakage current	I_{LO}	V_{OUT} =GND to V_{CC}	—	0.1	1	µA
Low level output voltage	V_{OL}	CMOS : I_{OL}=100 µA	—	—	0.1	V
		TTL : I_{OL}=2.1 mA	—	—	0.4	V
High level output voltage	V_{OH}	CMOS : I_{OH}=-100 µA	V_{CC} -0.1	—	—	V
		TTL : I_{OH}=-400 µA	2.4	—	—	V
Store inhibition voltage	V_{WI}		—	3.5	4.2	V
Schmitt width	V_{WD}	S-24S Series : $\overline{\text{STORE}}$ and $\overline{\text{RECALL}}$	0.4	—	—	V

■ Data Hold Characteristics

Table 5

Parameter	Symbol	Conditions	Min.	Typ.	Max	Unit
Data hold voltage	V_{DH}	CE≤0.2V, $\overline{\text{RECALL}}$≥V_{CC}-0.2V	1.5	—	5.5	V
Data hold setup time	t_{CDH}		50	—	—	ns
Recovery time	t_R		300	—	—	ns

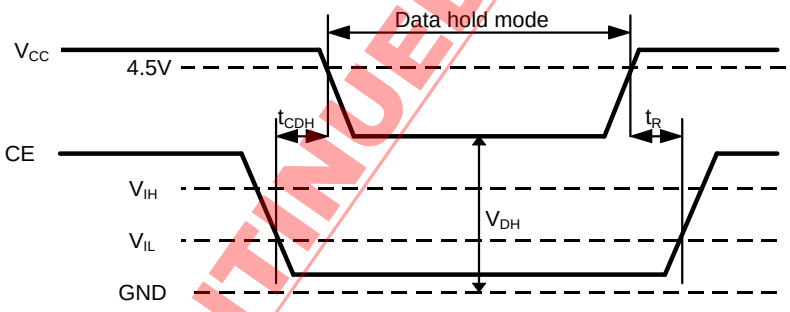


Figure 3 Data hold timing chart

DISCONTINUED PRODUCT

■ AC Electrical Chracteristics

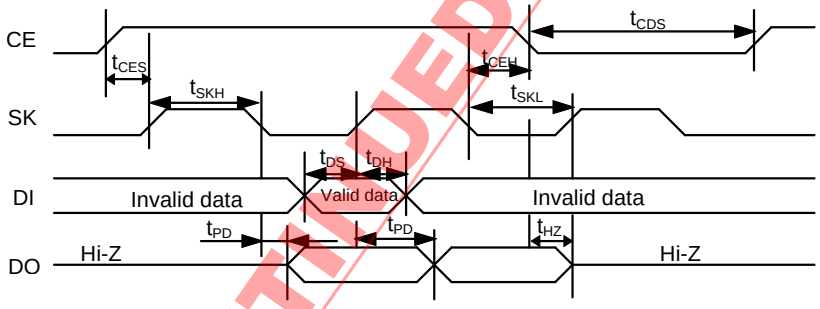
Table 6 Measuring conditions

Parameter	Conditions	
Input pulse voltage	S-24H Series : All inputs S-24S Series : CE, SK and DI	0.0 to 3.0 V
	S-24S Series : $\overline{\text{STORE}}$ and $\overline{\text{RECALL}}$	0.0 to 4.0 V
Input pulse rise/fall time		10 ns
I/O reference voltage		1.5 V
Output load		1TTL+100pF

1. Data input/output timing

Table 7

Parameter	Symbol	Min.	Typ.	Max	Unit
SK frequency	f_{SK}	—	—	1	MHz
SK high level pulse width	t_{SKH}	0.4	—	—	µs
SK low level pulse width	t_{SKL}	0.4	—	—	µs
Input data setup time	t_{DS}	0.4	—	—	µs
Input data hold time	t_{DH}	0.08	—	—	µs
SK data valid time	t_{PD}	—	—	0.3	µs
Output disable time	t_{HZ}	—	—	1.0	µs
CE setup time	t_{CES}	0.8	—	—	µs
CE hold time	t_{CEH}	0.4	—	—	µs
CE deselect time	t_{CDS}	0.8	—	—	µs



- CE must be kept high during instructions.
- When SK rises after selecting CE, the first 1 is taken into DI input and the fetch of an instruction starts. All previous 0 is ignored.

Figure 4 Control data timing

2. Recall Cycle

Table 8

Parameter	Symbol	Min.	Typ.	Max	Unit
Recall cycle time	t_{RCC}	2500	—	—	ns
Recall pulse width	t_{RCP}	500	—	—	ns
Recall disable time	t_{RCZ}	—	—	500	ns
Recall enable time	t_{ORC}	10	—	—	ns
Recall data access time	t_{ARC}	—	—	1000	ns

* Recall times are not limited.

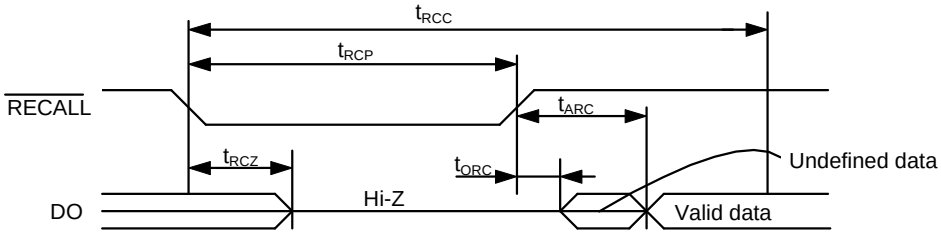


Figure 5 Hardware recall

DISCONTINUED PRODUCT

3. Store Cycle

Table 9

Parameter	Symbol	Min.	Typ.	Max	Unit
Store time	t_{ST}	—	—	10	ms
Store pulse width	t_{STP}	0.2	—	—	µs
Store disable time	t_{STZ}	—	—	1.0	µs

Store times: 10^5 times
Data retention : 10 years

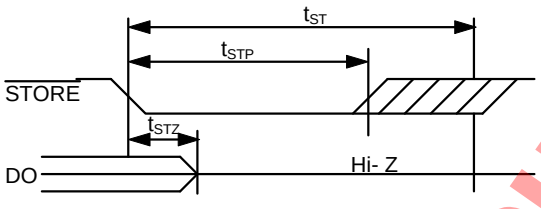


Figure 6 Hardware store

■ Instruction Set

Table 10

Instruction	Symbol	Format I_2 I_1 I_0	Function
Write enable latch reset	WRDS	1XXXX000	Reset write enable latch (Disable write and store)
Write enable latch set	WREN	1XXXX100	Set write enable latch (Enable write and store)
Read	READ	1AAAA11X	Read data from RAM address AAAA
Write	WRITE	1AAAA011	Write data into RAM address AAAA
Store	STO	1XXXX001	Store RAM data in E^2PROM
Recall	RCL	1XXXX101	Recall E^2PROM data into RAM
Sleep	SLEEP	1XXXX010	Enter sleep mode

X : Don't care
A : Address bit

- The format is composed of a start bit(1), address(A_3 A_2 A_1 A_0) and an instruction(I_2 I_1 I_0).
- Address A_0 is "X" for the S-24H30 and the S-24S30.

DISCONTINUED PRODUCT

■ Operation

1. Internal latches

The S-24 Series has two latches, one of which controls write operation of the SRAM, and both of which control permission/inhibition of store operation of the E^2PROM.

1.1 Previous recall latch

The previous recall latch controls permission/inhibition of store operation of E^2PROM. It is reset when the power is turned on, and it inhibits store operation of the E^2PROM. It is set by executing the software recall instruction or hardware recall, and it permits store operation of the E^2PROM.

1.2 Write enable latch

The write enable latch controls permission/inhibition of both store operation of the E^2PROM and write operation of the SRAM. It is reset when the power is turned on or by executing WRDS instruction, and it inhibits both store operation of the E^2PROM and write operation of the SRAM.

It is set by executing WREN instruction, and it permits both store operation of the E^2PROM and write operation of the SRAM.

When store operation of the E^2PROM is completed, the write enable latch is automatically reset. Therefore, in order to execute store operation again, it is necessary to execute WREN instruction and to set the write enable latch.

1.3 Both the previous recall latch and the write enable latch must be set for permission of store operation.

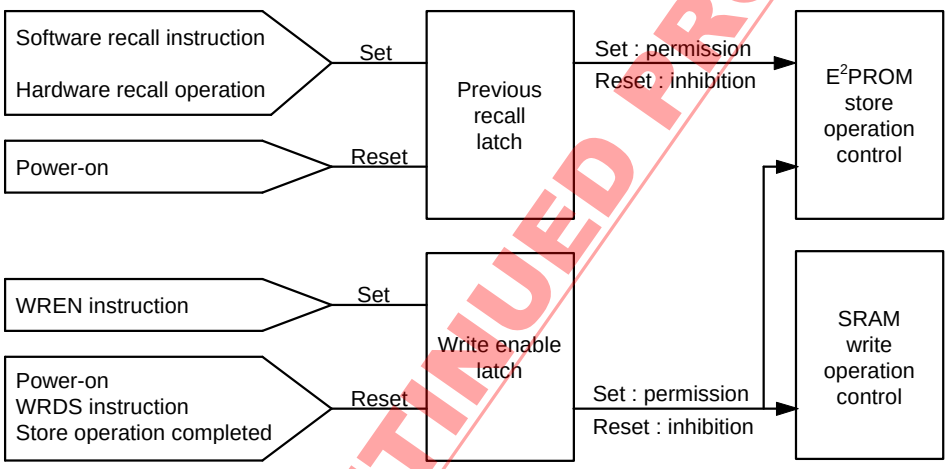


Figure 7 Internal latch

2. SRAM mode

2.1 Read

The data is read from the SRAM through READ instruction. Inputting a start bit, address and instruction code causes data output on DO. In the S-24 Series, a bi-directional serial interface can be made by connecting DI and DO. See Figures 8 and 9 for the timing.

2.2 Write

The data is written into the SRAM through WRITE instruction. Input data on DI after a start bit, address and instruction code. See Figures 10 and 11 for the timing. The write enable latch must be set before WRITE instruction.

DISCONTINUED PRODUCT

3. E^2PROM mode

Data is input to and output from the E^2PROM through the SRAM.

3.1 Store

The SRAM data is copied into the E^2PROM when STO instruction is executed or $\overline{\text{STORE}}$ goes low. The SRAM data does not change after STO instruction. Since the data stored in the E^2PROM is non-volatile, it is retained even if power is turned off. In the case that store operation is performed while data is output on DO and during read operation of the SRAM, DO becomes high-impedance. During store operation, all other operations are inhibited.

Both the previous recall latch and the write enable latch must be set before store operation.

3.2 Recall

The E^2PROM data is recopied into the SRAM when $\overline{\text{RECALL}}$ goes low or RCL instruction is executed. In the case that recall operation is performed while data is output on DO and during read operation of SRAM, DO becomes high-impedance. During recall operation, all other operations are inhibited.

4. Sleep mode

Executing SLEEP instruction disables operation of the SRAM. The E^2PROM data is retained. The sleep mode can be released by recall operation.
Since the S-24 Series is in standby status and the current consumption is low when CE is at GND level, it is not necessary to execute SLEEP instruction in order to reduce the current consumption while not operating.

5. Operation timing

After CE rose, when SK clock rises and DI goes high, a start bit is recognized and the fetch of an instruction starts. Data is fetched to DI terminal at the rise of SK clock.

5.1 Read

D0 is output at the fall of the 8th clock, and others are output at the rise of the clock.

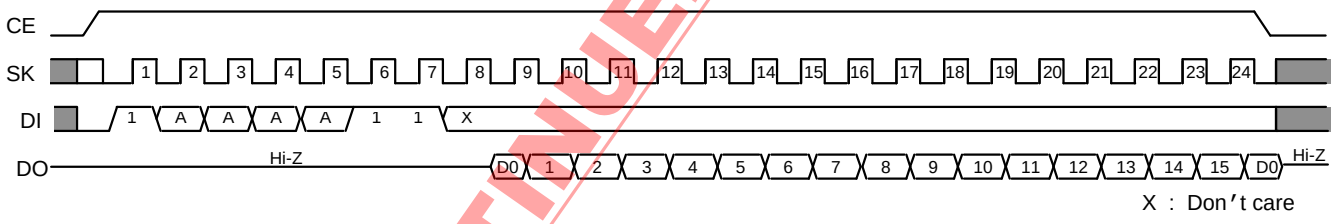


Figure 8 Read mode timing(S-24H45, S-24S45)

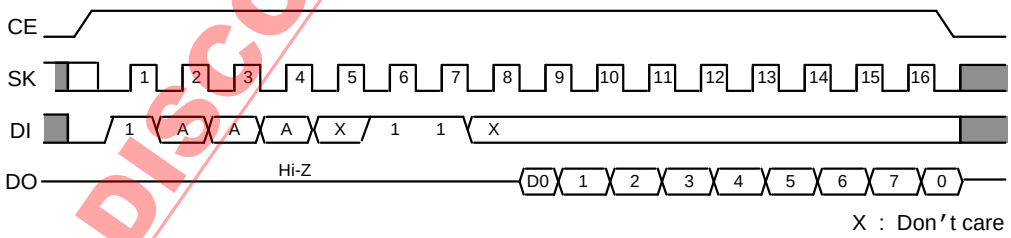


Figure 9 Read mode timing(S-24H30, S-24S30)

DISCONTINUED PRODUCT

5.2 Write

Data is written to the SRAM at the rise of SK clock.

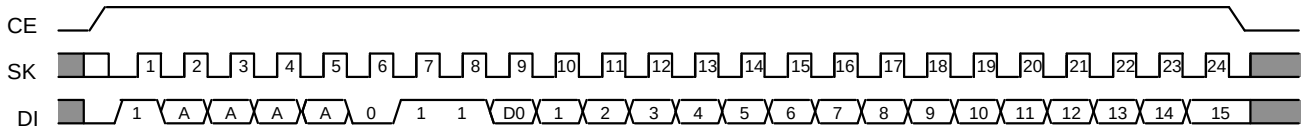


Figure 10 Write mode timing(S-24H45, S-24S45)

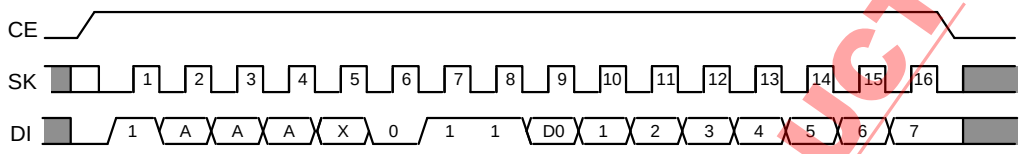


Figure 11 Write mode timing(S-24H30, S-24S30)

5.3 Other operation modes

CE must be low between instructions.

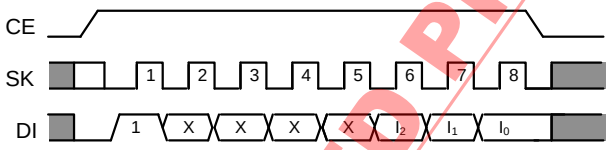


Figure 12 Other operation modes timing

DISCONTINUED PRODUCT

■ Interface with CPU with Serial Port

- When SK and DI are high at the rise of CE, high of DI is regarded as a start bit and the clock 1 generates and the high of DI is fetched. When DI is low, DI is not regarded as a start bit until DI becomes high at the rise of SK.
- After power on or after an instruction is performed, DI must be set 1 for preparing the fetch of the start bit of the next instruction.

Figures 13 to 17 show the timings of write/read, and other operation modes, and interfacing examples are shown in Figures 18 to 20.

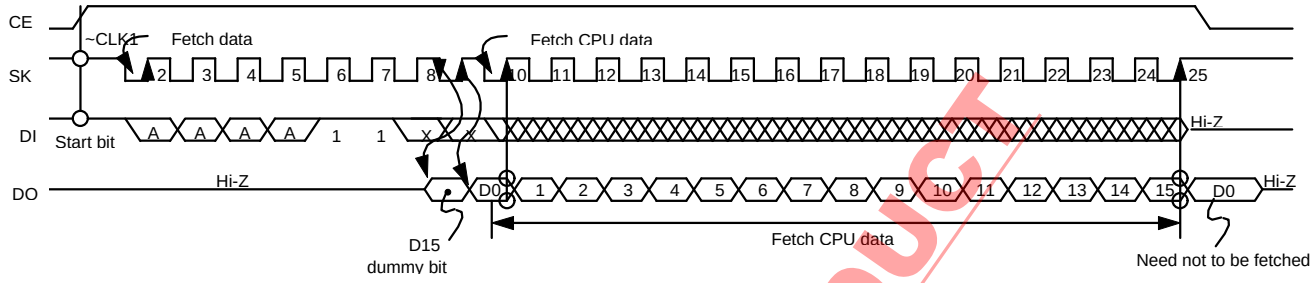


Figure 13 Read mode timing(S-24H45, S-24S45)

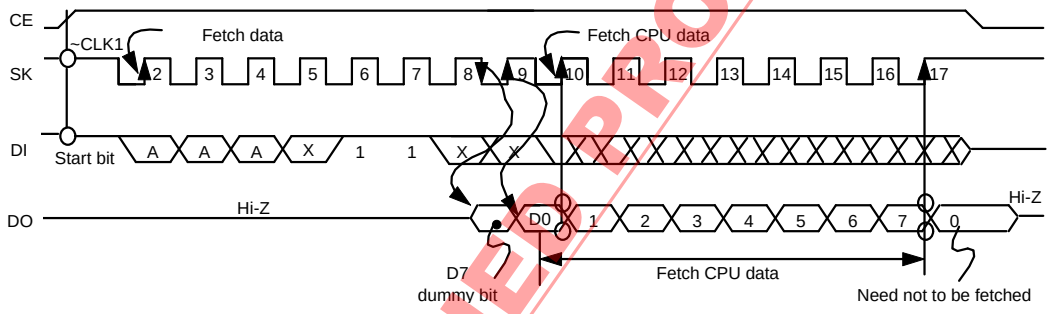


Figure 14 Read mode timing(S-24H30, S-24S30)

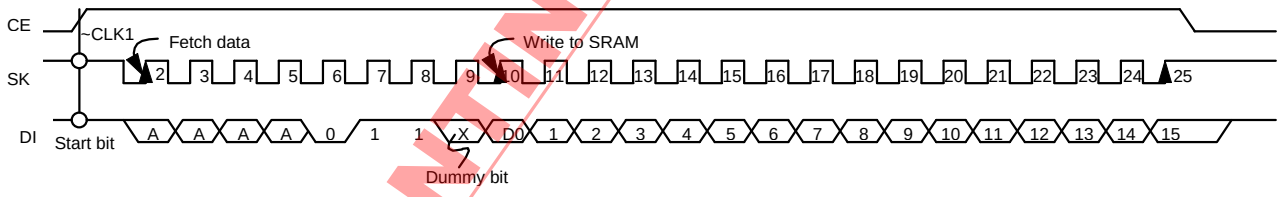


Figure 15 Write mode timing(S-24H45, S-24S45)

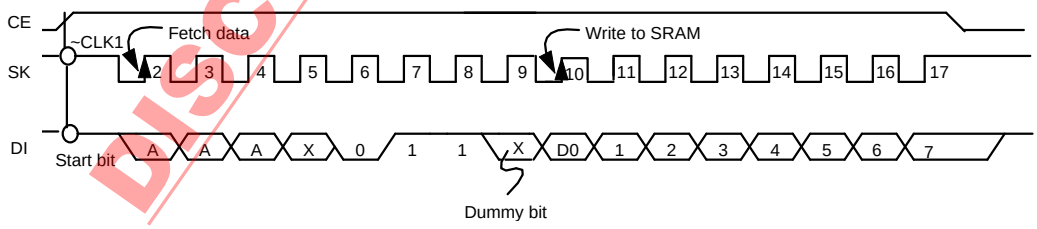


Figure 16 Write mode timing(S-24H30, S-24S30)

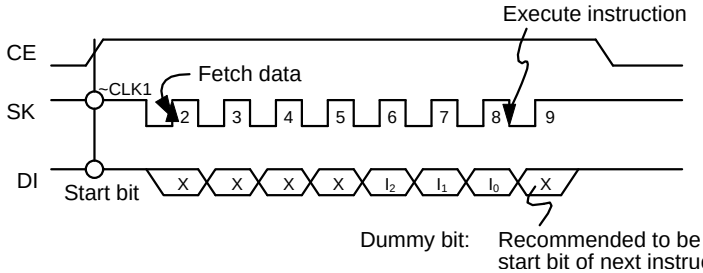


Figure 17 Other operation mode timing

DISCONTINUED PRODUCT

Interfacing example 1 : With Intel 8051, 8052

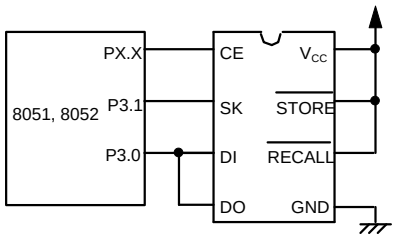


Figure 18

Interfacing example 2 : With other CPU

When the S-24 Series is connected to CPU other than Intel 8051 and 8052, delay circuit should be set by a capacitor and a resistor at DO terminal (Figure 19), delaying the signal more than 200 ns as in Figure 20 to assure the data hold time (t_{DHU}) and the data setup time (t_{DSU}) of CPU.

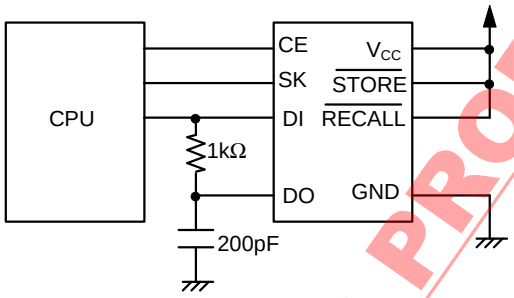


Figure 19

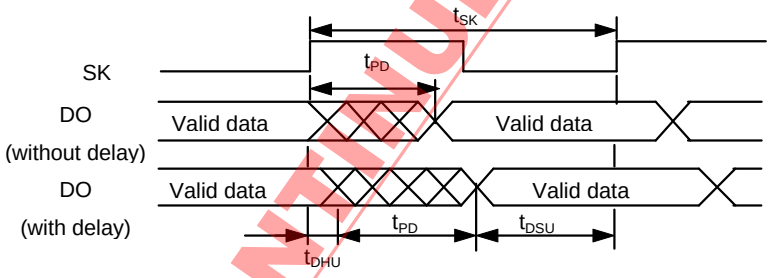


Figure 20

The maximum speed of the SK clock (f_{SKMAX}) is expressed by the following formula:

$$f_{SKMAX} = \frac{1}{t_{SK}} = \frac{1}{t_{DSU}+t_{DHU}+t_{PD}\,max.}$$

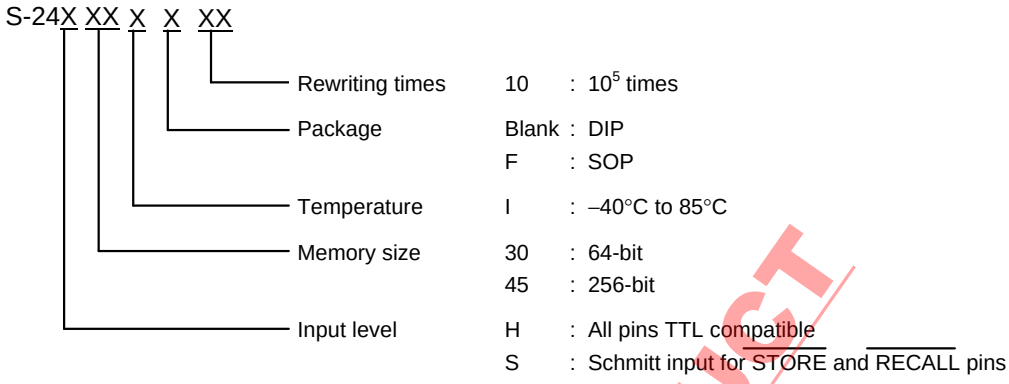
For example, when interfacing with NEC µPD75XX series, f_{SKMAX} is as follows:

µPD75XX series t_{DSU} : 300 ns min.
t_{DHU} : 450 ns min.
S-24 Series t_{PD} : 0 ns min. , 300 ns max.

$$f_{SKMAX} = \frac{1}{t_{SK}} = \frac{1\times10^{9}}{300+450+300} = \frac{1}{1.05\ \mu s} = 952\ kHz$$

DISCONTINUED PRODUCT

■ Ordering Information

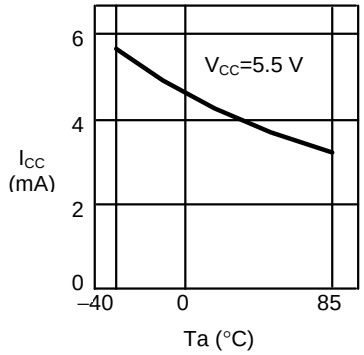


DISCONTINUED PRODUCT

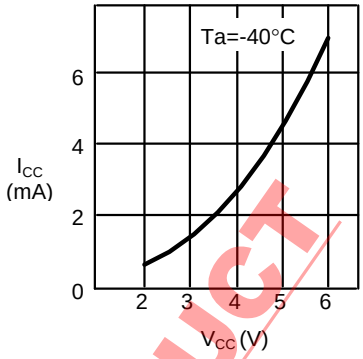
■ Characteristics

1. DC Characteristics

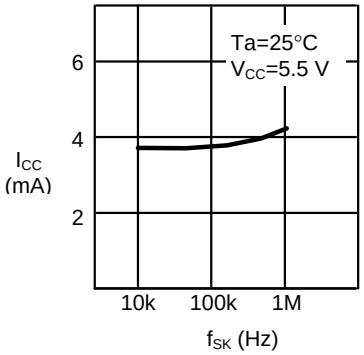
1.1 Operating current consumption I_{CC} – Ambient temperatureTa



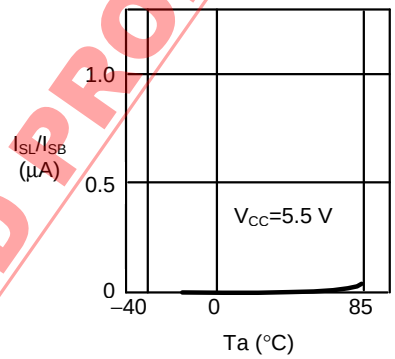
1.2 Operating current consumption I_{CC} – Power supply voltage V_{CC}



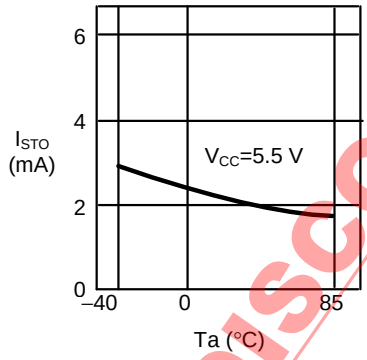
1.3 Operating current consumption I_{CC} – SK frequency f_{SK}



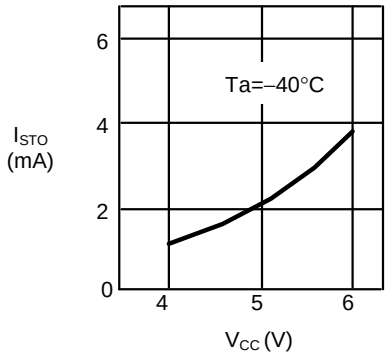
1.4 Sleep/standby current consumption I_{SL}/I_{SB} – Ambient temperature Ta



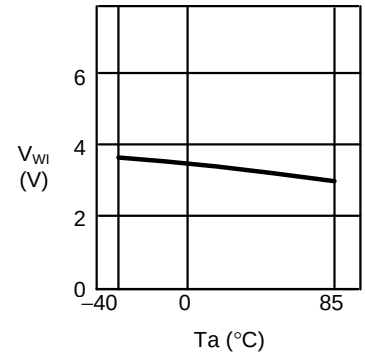
1.5 Store current consumption I_{STO} – Ambient temperature Ta



1.6 Store current consumption I_{STO} – Power supply voltage V_{CC}

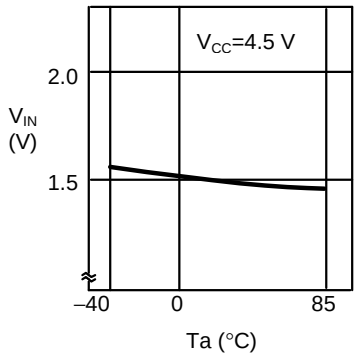


1.7 Store inhibition voltage V_{WI} – Ambient temperature Ta

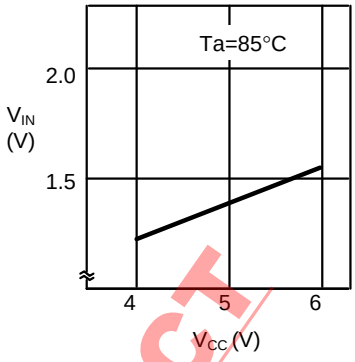


DISCONTINUED PRODUCT

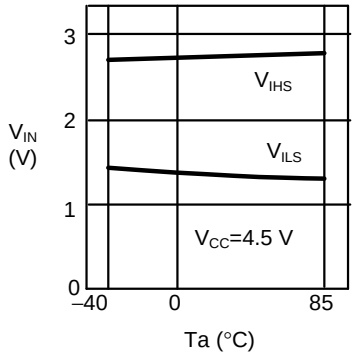
1.8 Input voltage V_{IN} – Ambient temperature Ta
S-24H Series : All inputs
S-24S Series : CE, SK and DI



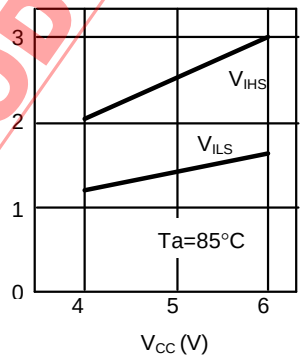
1.9 Input voltage V_{IN} – Power supply voltage V_{CC}
S-24H Series : All inputs
S-24S Series : CE, SK and DI



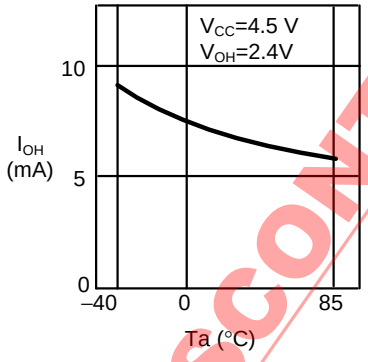
1.10 Input voltage V_{IN} – Ambient temperature Ta
S-24S Series : STORE and RECALL



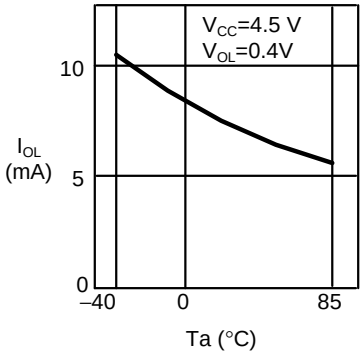
1.11 Input voltage V_{IN} – Power supply voltage V_{CC}
S-24S Series : STORE and RECALL



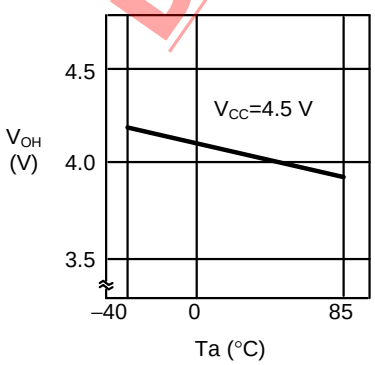
1.12 High level output current I_{OH} –
Ambient temperature Ta



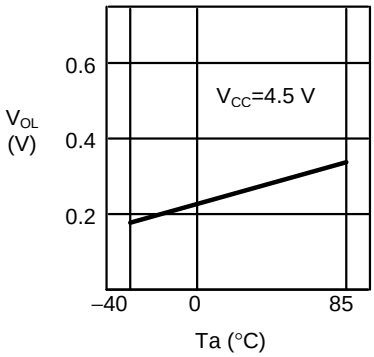
1.13 Low level output current I_{OL} –
Ambient temperature Ta



1.14 High level output voltage V_{OH} –
Ambient temperature Ta



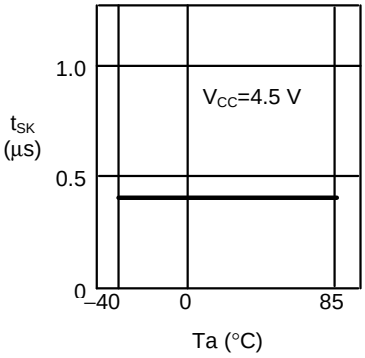
1.15 Low level output voltage V_{OL} –
Ambient temperature Ta



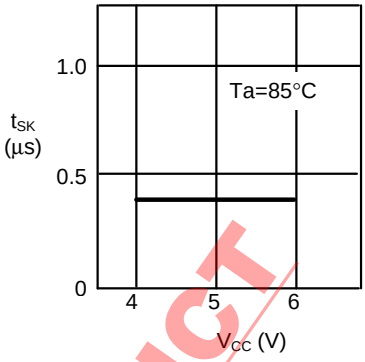
DISCONTINUED PRODUCT

2. AC Characteristics

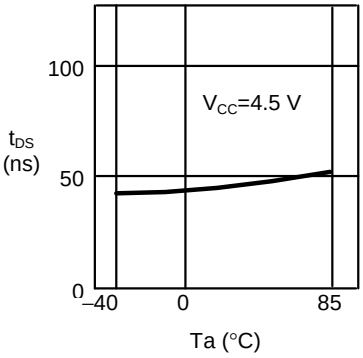
2.1 SK pulse width t_{SK} – Ambient temperature Ta



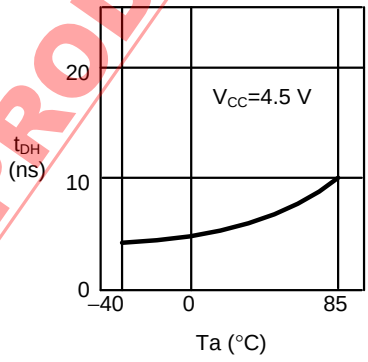
2.2 SK pulse width t_{SK} – Power supply voltage V_{CC}



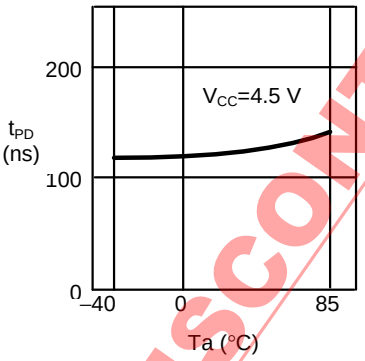
2.3 Input data setup time t_{DS} – Ambient temperature Ta



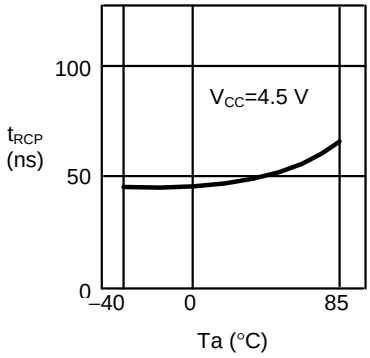
2.4 Input data hold time t_{DH} – Ambient temperature Ta



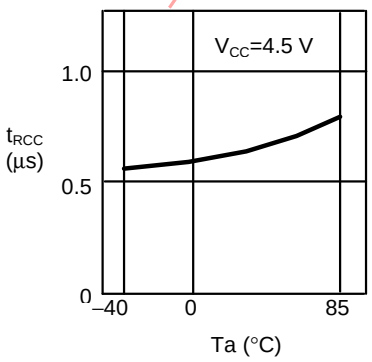
2.5 SK data valid time t_{PD} – Ambient temperature Ta



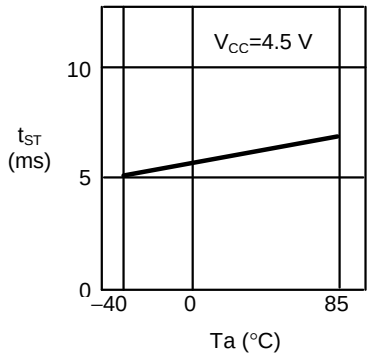
2.6 Recall pulse width t_{RCP} – Ambient temperature Ta



2.7 Recall cycle time t_{RCC} – Ambient temperature Ta

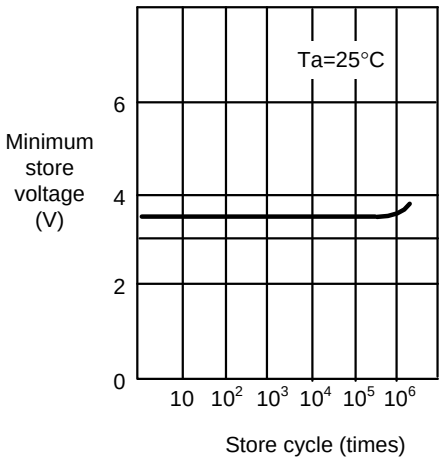


2.8 Store time t_{ST} – Ambient temperature Ta



DISCONTINUED PRODUCT

3. Rewriting Characteristics



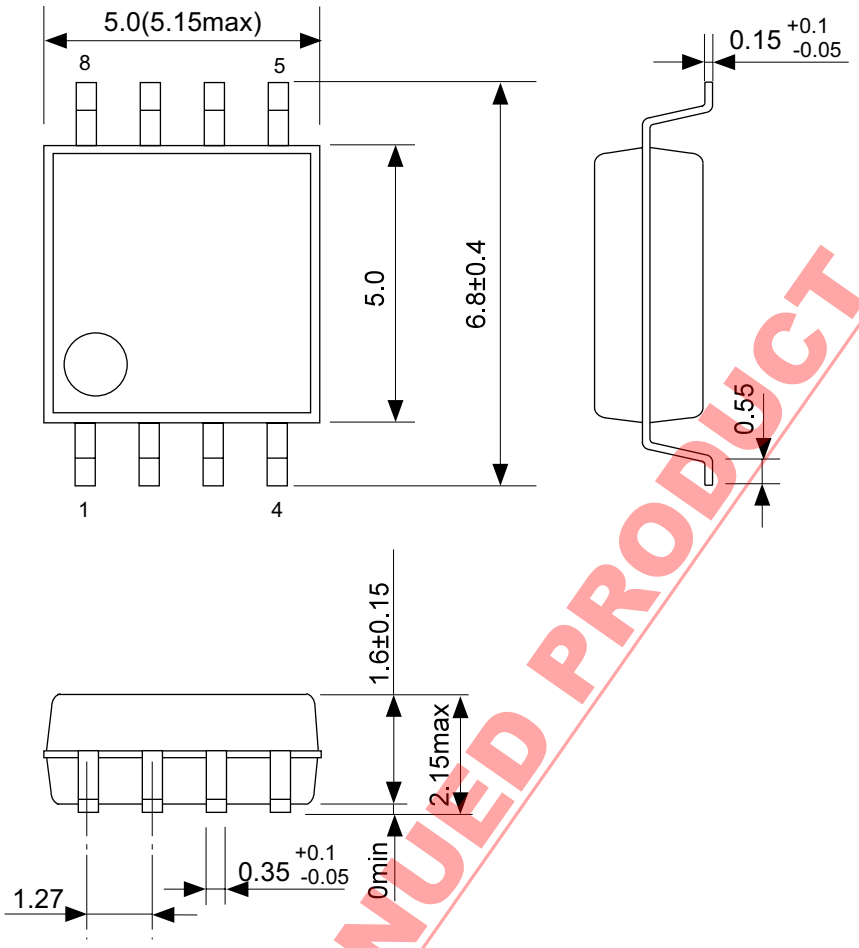
DISCONTINUED PRODUCT

■ 8-pin SOP

FE008-B 990531

●Dimensions

Unit:mm



No.：FE008－B－P－SD－1．0

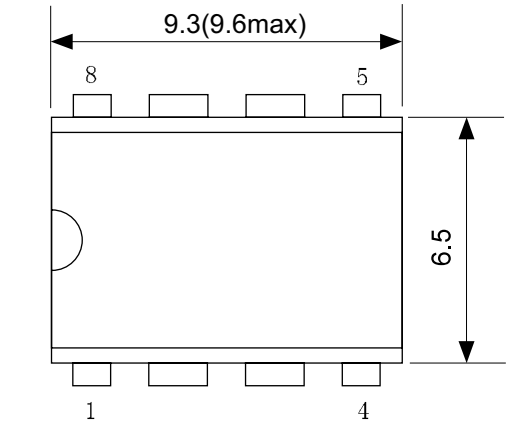
DISCONTINUED PRODUCT

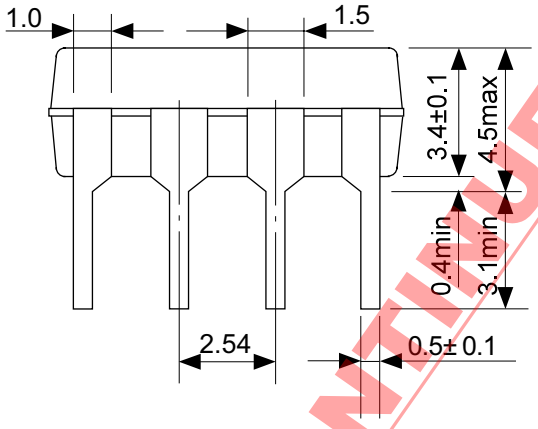
■ 8-pin DIP

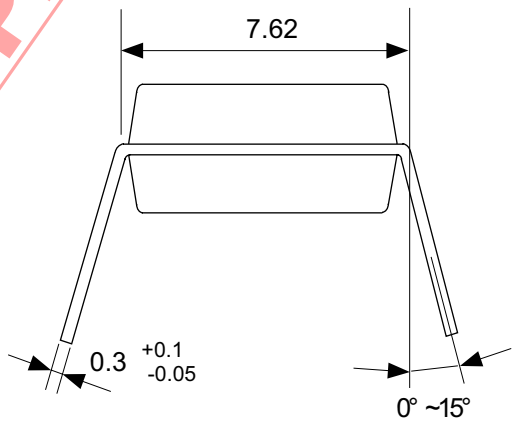
DP008-A 990531

●Dimensions

Unit:mm







No. ：ＤＰ００８－Ａ－Ｐ－ＳＤ－１．０

DISCONTINUED PRODUCT

DISCONTINUED PRODUCT

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